

Monolithic CMOS Analog Multiplexers

General Description

Maxim's DG508A and DG509A are monolithic CMOS analog multiplexers (muxes): the DG508A is a single 8-channel (1-of-8) mux, and the DG509A is a differential 4-channel (2-of-8) mux.

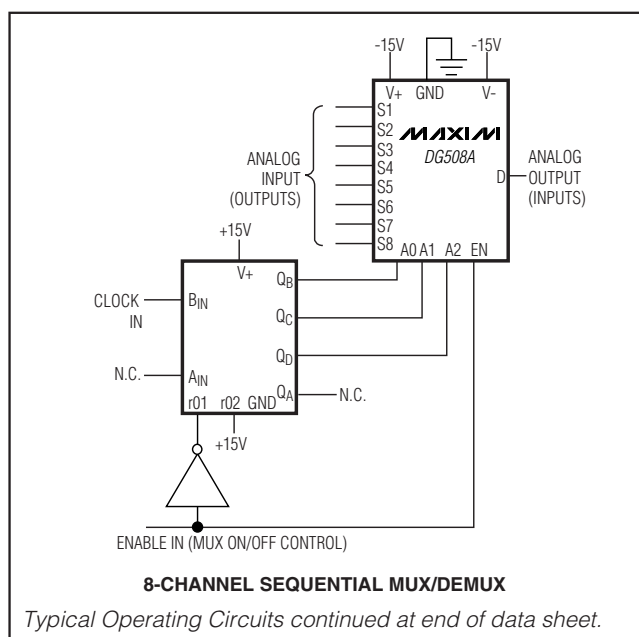
Both devices guarantee break-before-make switching. Maxim guarantees these muxes will not latch up if the power supplies are turned off with the input signals still present. Maxim also guarantees continuous operation when these devices are powered by supplies ranging from $\pm 4.5V$ to $\pm 18V$.

The DG508A/DG509A are plug-in upgrades for the industry-standard DG508A/DG509A, respectively. Maxim's parts have faster enable switching times and significantly lower leakage currents. The DG508A/DG509A also consume significantly lower power, making them ideal for portable equipment.

Applications

Control Systems
Data Logging Systems
Aircraft Heads-Up Displays
Data-Acquisition Systems
Signal Routing

Typical Operating Circuits



Features

- ◆ Improved Second Source
- ◆ Operate from $\pm 4.5V$ to $\pm 18V$ Supplies
- ◆ Symmetrical, Bidirectional Operation
- ◆ Logic and Enable Inputs, TTL and CMOS Compatible
- ◆ Latchup-Proof Construction
- ◆ Monolithic, Low-Power CMOS Design

Ordering Information

| PART | TEMP RANGE | PIN-PACKAGE |
|-------------|-----------------|----------------|
| DG508ACJ | 0°C to +70°C | 16 Plastic DIP |
| DG508ACWE | 0°C to +70°C | 16 Wide SO |
| DG508AC/D | 0°C to +70°C | Dice* |
| DG508ABK | -20°C to +85°C | 16 CERDIP |
| DG508ADJ | -40°C to +85°C | 16 Plastic DIP |
| DG508ADY | -40°C to +85°C | 16 Narrow SO |
| DG508AEWE | -40°C to +85°C | 16 Wide SO |
| DG508AAK | -55°C to +125°C | 16 CERDIP |
| DG508AMY/PR | -55°C to +125°C | 16 Narrow SO |
| DG509ACJ | 0°C to +70°C | 16 Plastic DIP |
| DG509ACWE | 0°C to +70°C | 16 Wide SO |
| DG509AC/D | 0°C to +70°C | Dice* |
| DG509ABK | -20°C to +85°C | 16 CERDIP |
| DG509ADJ | -40°C to +85°C | 16 Plastic DIP |
| DG509ADY | -40°C to +85°C | 16 Narrow SO |
| DG509AEWE | -40°C to +85°C | 16 Wide SO |
| DG509AAK | -55°C to +125°C | 16 CERDIP |
| DG509AMY/PR | -55°C to +125°C | 16 Narrow SO |

Devices are available in a lead(Pb)-free/RoHS-compliant package (except CERDIP). Specify lead-free by adding a plus (+) to the part number when ordering.

*Contact factory for dice specifications.

Monolithic CMOS Analog Multiplexers

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-

| | |
|--|---|
| V+ | +44V |
| GND | +25V |
| Digital Inputs, V _S and V _D (Note 1) | -2V to (V+ + 2V) or 20mA, whichever occurs first |
| Current (any terminal, except S or D) | 30mA |
| Continuous Current, S or D | 20mA |
| Peak Current, S or D (pulsed at 1ms, 10% duty cycle max) .. | 40mA |
| Continuous Power Dissipation (T _A = +70°C) | |
| Plastic DIP (derate 10.53mW/°C above +70°C) | 842mW |
| Narrow SO (derate 8.70mW/°C above +70°C) | 696mW |
| Wide SO (derate 9.52mW/°C above +70°C) | 762mW |
| CERDIP (derate 10.00mW/°C above +70°C) | 800mW |

Operating Temperature Ranges:

| | |
|--|-----------------|
| DG50_ACJ/CWE | 0°C to +70°C |
| DG50_ABK | -20°C to +85°C |
| DG50_ADJ/DY/EWE | -40°C to +85°C |
| DG50_AAK/MY | -55°C to +125°C |
| Storage Temperature Range | -65°C to +150°C |
| Lead Temperature (soldering, 10s) | +300°C |
| Soldering Temperature (reflow) | |
| PDI, Wide SO, Narrow SO, CERDIP containing lead(Pb) .. | +240°C |
| PDI, Wide SO, Narrow SO lead(Pb)-free | +260°C |

Note 1: Signals on S₋ or D₋ exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V+ = 15V, V- = -15V, V_{GND} = 0V, T_A = +25°C, unless otherwise noted.)

| PARAMETER | SYMBOL | CONDITIONS | DG508AA/M DG509AA/M | | | DG508AD/E/B/C DG509AD/E/B/C | | | UNITS |
|--|----------------------|--|--|-----|-------|--------------------------------|-------|--------|-------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| SWITCH | | | | | | | | | |
| Analog Signal | V _{ANALOG} | | -15 | | +15 | -15 | | +15 | V |
| Drain-Source On-Resistance | R _{DS(ON)} | Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V (Note 4) | V _D = 10V, I _S = -200μA | | 170 | 400 | 170 | 450 | Ω |
| | | | V _D = -10V, I _S = 200μA | | 130 | 400 | 130 | 450 | |
| Greatest Change in Drain-Source On-Resistance Between Channels | ΔR _{DS(ON)} | $\Delta R_{DS(ON)} = \left(\frac{R_{DS(ON) \max} - R_{DS(ON) \min}}{R_{DS(ON)}} \right)$ | | | 6 | | 6 | | % |
| Source Off-Leakage Current | I _{S(OFF)} | V _{EN} = 0V | V _S = 10V, V _D = -10V | | 0.002 | 0.5 | 0.002 | 1 | nA |
| | | | V _S = -10V, V _D = 10V | | -0.5 | -0.005 | -1 | -0.005 | |
| Drain Off-Leakage Current | DG508A | V _{EN} = 0V | V _D = 10V, V _S = -10V | | 0.01 | 2 | 0.01 | 5 | nA |
| | | | V _D = -10V, V _S = 10V | | -2 | -0.015 | -5 | -0.015 | |
| | DG509A | | V _D = 10V, V _S = -10V | | 0.005 | 2 | 0.005 | 5 | |
| | | | V _D = -10V, V _S = 10V | | -2 | -0.008 | -5 | -0.008 | |
| Drain On-Leakage Current | DG508A | Sequence each switch on, V _{A_L} = 0.8V V _{A_H} = 2.4V (Note 2) | V _{S(all)} = V _D = 10V | | 0.015 | 2 | 0.015 | 5 | nA |
| | | | V _{S(all)} = V _D = -10V | | -2 | -0.03 | -5 | -0.03 | |
| | DG509A | | V _{S(all)} = V _D = 10V | | 0.007 | 2 | 0.007 | 5 | |
| | | | V _{S(all)} = V _D = -10V | | -2 | -0.015 | -5 | -0.015 | |

Monolithic CMOS Analog Multiplexers

DG508A/DG509A

ELECTRICAL CHARACTERISTICS (continued)

(V+ = 15V, V- = -15V, VGND = 0V, TA = +25°C, unless otherwise noted.)

| PARAMETER | SYMBOL | CONDITIONS | DG508AA/M DG509AA/M | | | DG508AD/E/B/C DG509AD/E/B/C | | | UNITS |
|--|-------------|--|-------------------------------|-------|-------|--------------------------------|--------|-----|-------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| LOGIC INPUT | | | | | | | | | |
| Logic Input Current, Input Voltage High | IAH | VA_ = 2.4V | | -10 | - | 10 | -0.002 | μA | |
| | | VA_ = 15V | | 0.006 | 10 | 0.006 | 10 | | |
| Logic Input Current, Input Voltage Low | IAL | All VA_ = 0V | VEN = 2.4V | -10 | - | 10 | -0.002 | μA | |
| | | | VEN = 0V | -10 | - | -10 | -0.002 | | |
| DYNAMIC | | | | | | | | | |
| Multiplexer Switching | ttransition | Figure 1 | | 0.6 | 1.0 | 0.6 | 1.0 | μs | |
| Break-Before-Make Interval | tOPEN | Figure 3 | | 0.2 | | 0.2 | | μs | |
| Enable Turn-On Time | tON(EN) | Figure 2 | | 0.4 | 1.0 | 0.4 | 1.5 | μs | |
| Enable Turn-Off Time | tOFF(EN) | Figure 2 | | 0.2 | 0.7 | 0.2 | 1.0 | μs | |
| Off-Isolation | OIRR | VEN = 0V, RL = 1kΩ, CL = 15pF, VS = 7VRMS f = 500kHz (Note 3) | | 68 | | 68 | | dB | |
| Source Off-Capacitance | CS(OFF) | VS = 0V, VEN = 0V, f = 140kHz | | 5 | | 5 | | pF | |
| Drain Off- Capacitance | IDG508A | CD(OFF) | VS = 0V, VEN = 0V, f = 140kHz | 25 | | 25 | | pF | |
| | DGS09A | | | 12 | | 12 | | | |
| SUPPLY | | | | | | | | | |
| Positive Supply Current | I+ | VEN = 2.4V, all VA_ = 0V or 2.4V | | 0.02 | 0.2 | 0.02 | 0.2 | mA | |
| Negative Supply Current | I- | VEN = 2.4V, all VA_ = 0V or 2.4V | | -0.1 | -0.01 | -0.1 | -0.01 | mA | |
| Positive Supply Current in Standby | I+ | VEN = 0V, all VA_ = 0V or 2.4V | | 0.02 | 0.2 | 0.02 | 0.2 | mA | |
| Negative Supply Current in Standby | I- | VEN = 0V, all VA_ = 0V or 2.4V | | -0.1 | -0.01 | -0.1 | -0.01 | mA | |
| Power-Supply Range for Continuous Operation | V-, V+ | (Notes 4, 5) | | ±4.5 | ±18.0 | ±4.5 | ±18.0 | V | |

Monolithic CMOS Analog Multiplexers

ELECTRICAL CHARACTERISTICS

(V₊ = 15V, V_{GND} = 0V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

| PARAMETER | SYMBOL | CONDITIONS | DG508AA/M DG509AA/M | | | DG508AD/E/B/C DG509AD/E/B/C | | | UNITS |
|---|---------------------|---|---|--|------|--------------------------------|------|------|-------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| SWITCH | | | | | | | | | |
| Analog Signal Range | V _{ANALOG} | | -15 | +15 | | -15 | +15 | | V |
| Drain-Source On-Resistance | R _{DS(ON)} | Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V | V _D = 10V, I _S = -200μA | 500 | | 550 | | | Ω |
| | | | V _D = -10V, I _S = 200μA | 500 | | 550 | | | |
| Source Off-Leakage Current | I _{S(OFF)} | V _{EN} = 0V | V _S = 10V, V _D = -10V V _S = -10V, V _D = -10V | | +50 | | +50 | | nA |
| Drain Off-Leakage Current | DG508A DG509A | I _{D(OFF)} | V _{EN} = 0V | V _D = 10V, V _S = -10V | | +200 | | +100 | nA |
| | | | | V _D = -10V, V _S = -10V | -200 | | -200 | | |
| | | | | V _D = 10V, V _S = -10V | | +200 | | +100 | |
| | | | | V _D = -10V, V _S = -10V | -100 | | -100 | | |
| Drain On-Leakage Current | DG508A DG509A | I _{D(ON)} | Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V (Note 2) | V _{S(all)} = V _D = 10V | | +200 | | +100 | nA |
| | | | | V _{S(all)} = V _D = -10V | -200 | | -100 | | |
| | | | | V _{S(all)} = V _D = 10V | | +100 | | +100 | |
| | | | | V _{S(all)} = V _D = -10V | -100 | | -100 | | |
| LOGIC INPUT | | | | | | | | | |
| Logic Input Current, Input Voltage High | I _{AH} | V _{A_} = 2.4V | | -30 | | -30 | | | μA |
| | | V _{A_} = 15V | | | +30 | | +30 | | |
| Logic Input Current, Input Voltage Low | I _{AL} | All V _{A_} = 0V | V _{EN} = 2.4V | -30 | | -30 | | | μA |
| | | | V _{EN} = 0V | -30 | | -30 | | | |

Note 2: I_{D(ON)} is leakage from driver into on switch.

Note 3: Off-isolation = 20log $\frac{|V_S|}{|V_D|}$

V_S = input to off switch,
V_D = output due to V_S.

Note 4: Electrical characteristics (such as on-resistance) change when power supplies other than ±15V are used.

Note 5: For designs requiring single 5V or dual ±5V operation, refer to Maxim's improved MAX338 and MAX339. Minimum operating voltage for DG508ADY/MY and DG509ADY/MY is ±9V.

Monolithic CMOS Analog Multiplexers

DG508A/DG509A

Pin Configurations



Pin Descriptions

| PIN | | NAME | FUNCTION |
|------------------|------------------|------------|-------------------------------|
| DG508A DIP/SO | DG509A DIP/SO | | |
| 1, 15, 16 | — | A0, A2, A1 | Address Input |
| — | 1, 16 | A0, A1 | Address Input |
| 2 | 2 | EN | Enable |
| 3 | 3 | V- | Negative-Supply Voltage Input |
| 4-7 | — | S1-S4 | Analog Inputs, Bidirectional |
| — | 4-7 | S1A-S4A | Analog Inputs, Bidirectional |
| 8 | — | D | Analog Outputs, Bidirectional |
| — | 8, 9 | DA, DB | Analog Outputs, Bidirectional |
| 9-12 | — | S8-S5 | Analog Inputs, Bidirectional |
| — | 10-13 | S4B-S1B | Analog Inputs, Bidirectional |
| 13 | 14 | V+ | Positive-Supply Voltage Input |
| 14 | 15 | GND | Ground |

Functional Diagrams



Monolithic CMOS Analog Multiplexers

DG508A/DG509A

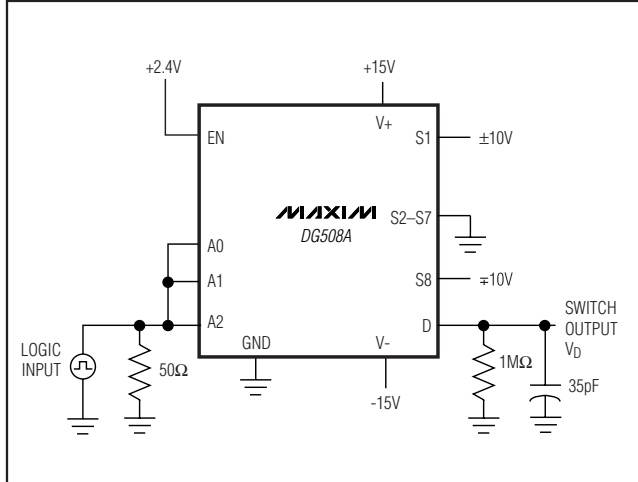


Figure 1a. Switching-Time Test Circuit

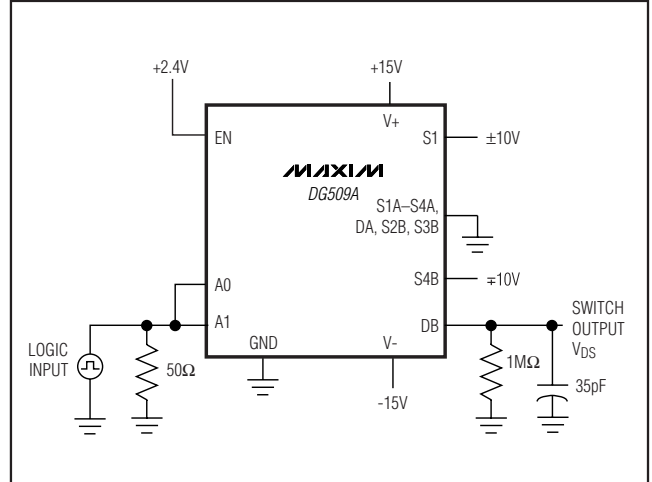


Figure 1b. Switching-Time Test Circuit



Figure 2a. DG508A Enable-Time Test Circuit



Figure 2b. DG509A Enable-Time Test Circuit

Monolithic CMOS Analog Multiplexers

DG508A/DG509A



Figure 3. Break-Before-Make Test Circuit



Figure 4. Timing Diagram for Figures 1, 2, and 3

Table 1a. DG508A Truth Table

| A2 | A1 | A0 | EN | ON SWITCH |
|----|----|----|----|-----------|
| X | X | X | 0 | NONE |
| 0 | 0 | 0 | 1 | 1 |
| 0 | 0 | 1 | 1 | 2 |
| 0 | 1 | 0 | 1 | 3 |
| 0 | 1 | 1 | 1 | 4 |
| 1 | 0 | 0 | 1 | 5 |
| 1 | 0 | 1 | 1 | 6 |
| 1 | 1 | 0 | 1 | 7 |
| 1 | 1 | 1 | 1 | 8 |

X = Don't care.

Table 1b. DG509A Truth Table

| A1 | A0 | EN | ON SWITCH |
|----|----|----|-----------|
| X | X | 0 | NONE |
| 0 | 0 | 1 | 1 |
| 0 | 1 | 1 | 2 |
| 1 | 0 | 1 | 3 |
| 1 | 1 | 1 | 4 |

X = Don't care.

Monolithic CMOS Analog Multiplexers

Typical Operating Circuits (continued)



Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

| PACKAGE TYPE | PACKAGE CODE | DOCUMENT NO. |
|----------------|--------------|-------------------------|
| 16 Plastic DIP | P16-1 | 21-0043 |
| 16 Wide SO | W16-2 | 21-0042 |
| 16 Narrow SO | S16-5 | 21-0041 |
| 16 CERDIP | J16-3 | 21-0045 |

Monolithic CMOS Analog Multiplexers

Revision History

| REVISION NUMBER | REVISION DATE | DESCRIPTION | PAGES CHANGED |
|-----------------|---------------|---|---------------|
| 4 | 5/10 | Updated the "Drain-Source On-Resistance" parameter for both the $T_A = +25^\circ\text{C}$ and $T_A = T_{\text{MIN}}$ to T_{MAX} conditions. | 2, 4 |
| | | Deleted the QFN package from the <i>Ordering Information</i> , <i>Absolute Maximum Ratings</i> , <i>Pin Configurations</i> , <i>Pin Descriptions</i> , and <i>Package Information</i> sections. | 1, 2, 5, 8 |
| | | Added the DG508AMY/PR and DG509AMY/PR parts to the <i>Ordering Information</i> table. | 1 |

DG508A/DG509A

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600 _____ 9

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9